

## PREPARATION AND CHARACTERIZATION OF LOW VOLTAGE TIN OXIDE VARISTORS

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Varistors are polycrystalline ceramics of high density with non-ohmic properties that depend on typical grain boundary phenomena<sup>1</sup>. The electrical properties are highly dependent on the resultant microstructure that is dependent on chemical composition, sintering and grain size<sup>2</sup> of the powder of the composition (98,9%SnO<sub>2</sub>+0,5%CoO+0,05%Nb<sub>2</sub>O<sub>5</sub>+0,05%Cr<sub>2</sub>O<sub>3</sub>+0,5%Bi<sub>2</sub>O<sub>3</sub>)<sup>3</sup>. The calcined powders with different grains size, which ranged from 6 to 12 µm. The powders were conformed at 100 MPa and then sinterized at 1350 °C for 120, 240 e 360 min in tubular furnace with a heating and cooling rate of 3 °C/min. The results showed that non-linear electric properties depend on the grain size that, on the other hand depend on the time of sintering<sup>4</sup>. These samples obtained grains the most of 80µm, decreasing the number of barriers by unit length. The samples with bismuth oxide replacing partially the cobalt showed order broken-down voltage reduction of 3300 V/cm, reaching 600v/cm with  $\alpha$  between 1,6 and 6 and densities between 90% and 93,6% of pure tin oxide. The crystalline phases were characterized by XRD and EDX methods. Thus, it was found that cassiterite (SnO<sub>2</sub>) is the primary phase and cobalt stannate (Co<sub>2</sub>SnO<sub>4</sub>) is the secondary phase, yet showed in other samples without bismuth oxide dopant<sup>5</sup>.

### References:

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